Diode Semiconductor Device - Page 1 of 1



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Inclosure Mate	erial:
Metal	
Overall Lengtl	h:
1.438 inches	
Overall Diame	ter:
0.667 inches	
Mounting Fac	ility Quantity:
1	
Mounting Met	hod:
Threaded stud	
Features Prov	ided:
Hermetically se	ealed case
Overall Width	Across Flats:
0.677 inches	
Thread Size:	
0.250 inches	
Semiconducto	or Material:
Silicon	
Voltage Rating	g In Volts Per Characteristic:
20.0 reverse v	oltage, instantaneous and 24.0 reverse voltage, peak and 20.0 working peak reverse voltage
Current Rating	g Per Characteristic:
40.00 amperes	forward current, average absolute
Maximum Ope	erating Tempurature Per Measurement Point:
125.0 degrees	celsius junction
Thread Series	Designator:
Unf	
Terminal Type	And Quantity:
1 tab, solder lu	ug and 1 threaded stud
Shelf Life:	
N/a	
Unit Of Measu	ire:
Demilitarizatio	on:
No	
Fiig:	
A110a0	